NSN 5961-00-852-3359

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-852-3359 **Inclosure Material:** Glass **Overall Length:** 0.300 inches **Terminal Length:** 1.000 inches **Overall Diameter:** Between 0.125 inches and 0.150 inches **Mounting Method:** Terminal Features Provided: Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 3.6 regulator voltage **Current Rating Per Characteristic:** 20.00 milliamperes repetitive peak forward current **Power Rating Per Characteristic:** 400.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 80131-release2491 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0